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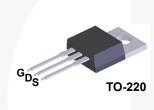
FDP3672

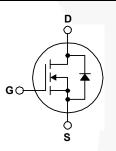
N-Channel PowerTrench[®] MOSFET 105 V, 41 A, 33 m Ω

Features

- $R_{DS(on)}$ = 25 m Ω (Typ.) @ V_{GS} = 10 V, I_D = 41 A
- $Q_{G(tot)} = 28 \text{ nC} (Typ.) @ V_{GS} = 10 \text{ V}$
- Low Miller Charge
- Low Q_{rr} Body Diode
- Optimized Efficiency at High Frequencies
- UIS Capability (Single Pulse and Repetitive Pulse)

Formerly developmental type 82760





Motor drives and Uninterruptible Power Supplies

MOSFET Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	FDP3672	Unit V	
V _{DSS}	Drain to Source Voltage	105		
V _{GS}	Gate to Source Voltage	±20	V	
	Drain Current			
I _D	Continuous ($T_c = 25^{\circ}C$, $V_{GS} = 10V$)	41	А	
	Continuous ($T_c = 100^{\circ}C$, $V_{GS} = 10V$)	31	A	
	Continuous ($T_{amb} = 25^{\circ}C$, $V_{GS} = 10V$, $R_{\theta JA} = 62^{\circ}C/W$)	5.9	A	
	Pulsed	Figure 4	A	
E _{AS}	Single Pulse Avalanche Energy (Note 1)	48	mJ	
P _D	Power dissipation	135	W	
	Derate above 25°C	0.9	W/°C	
T _J , T _{STG}	Operating and Storage Temperature	-55 to 175	°C	

Applications

Consumer Appliances

Synchronous Rectification

Battery Protection Circuit

· Micro Solar Inverter

Thermal Characteristics

$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	1.11	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient, Max. (Note 2)	62	°C/W

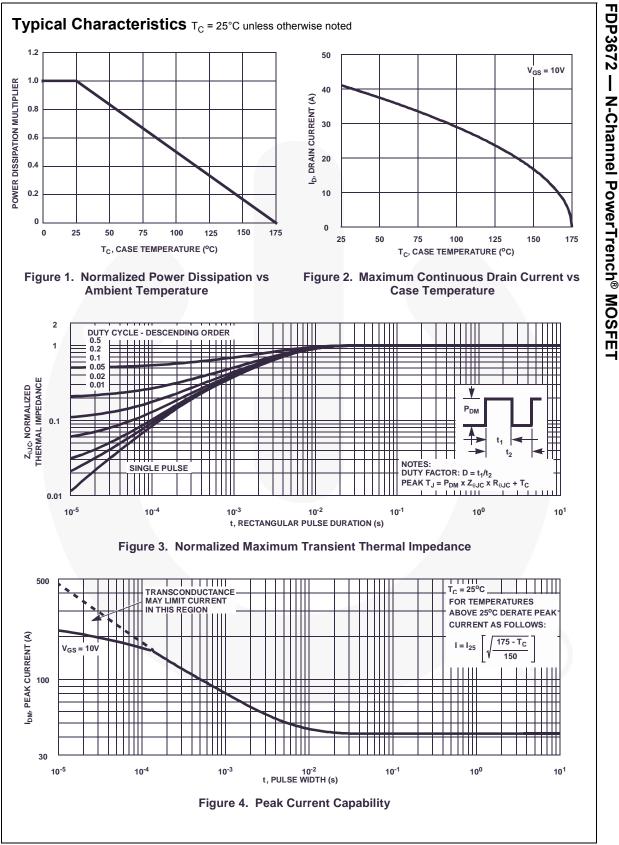
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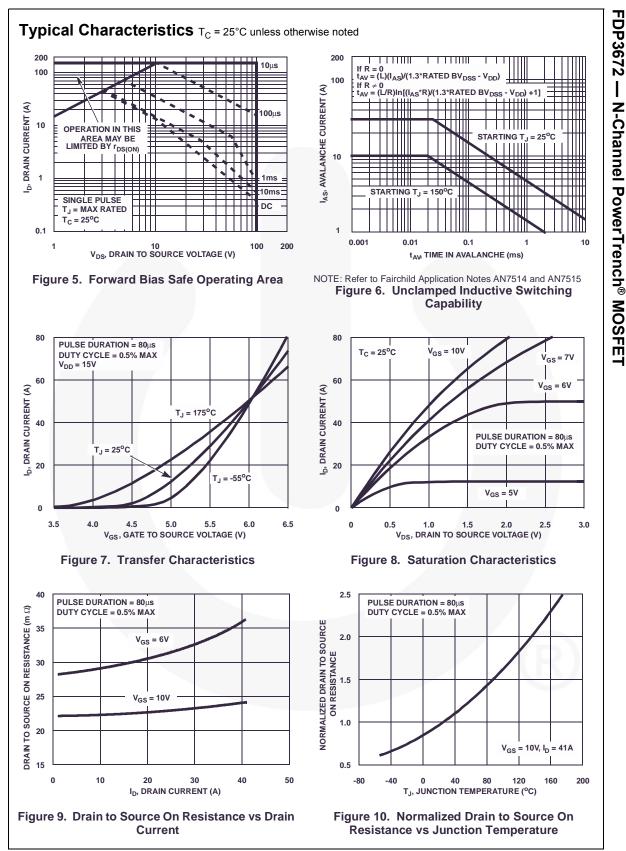
November 2013

Device Marking FDP3672		Device Package Reel Size		Reel Size	Tape Width		Quantity 50 units					
		FDP3672	TO-220 Tube									
Electrical Characteristics T _C = 25°C unless otherwise noted												
Symbol		Parameter	Test	Conditions	Min	Тур	Max	Unit				
Off Chara	cteristic	S										
B _{VDSS}	Drain to S	Source Breakdown Voltage	I _D = 250μA,	$V_{GS} = 0V$	105	-	-	V				
	Zero Cat	Zero Gate Voltage Drain Current		V _{DS} = 80V		-	1					
I _{DSS} Zero Gate			$V_{GS} = 0V$	T _C = 150°C	-	-	250	μΑ				
I _{GSS}	Gate to S	Gate to Source Leakage Current		$V_{GS} = \pm 20V$		-	±100	nA				
On Chara	cteristic	S										
V _{GS(TH)}			$V_{GS} = V_{DS}$	$V_{GS} = V_{DS}, I_D = 250 \mu A$		-	4	V				
		0-	I _D = 41A, V ₀		-	0.025	0.033	<u> </u>				
r	Drain to 6	Source On Posistones		$I_D = 21A, V_{GS} = 6V,$		0.031	0.055	0				
r _{DS(ON)}	Diamito c	Drain to Source On Resistance		$I_D = 41A, V_{GS} = 10V,$ $T_C = 175^{\circ}C$		0.063	0.070	Ω				
Dynamic	Characte	eristics				L						
C _{ISS}	Input Cap				-	1670	-	pF				
C _{OSS}		apacitance	$V_{DS} = 25V,$	$V_{GS} = 0V,$		240	-	pF				
C _{RSS}	-	Transfer Capacitance	f = 1MHz			55	-	pF				
Q _{g(TOT)}	-	e Charge at 10V	$V_{GS} = 0V to$	10V	-	28	37	nC				
Q _{g(TH)}	Threshold	d Gate Charge	$V_{GS} = 0V tc$		-	3.9	5	nC				
Q _{gs}	Gate to S	ource Gate Charge		I _D = 41A	-	12	-	nC				
Q _{gs2}	Gate Cha	rge Threshold to Plateau		l _g = 1.0mA	-	8.0	-	nC				
Q _{gd}	Gate to D	orain "Miller" Charge			-	6.5	-	nC				
	1	ng Characteristics (V	_{GS} = 10V)		_							
t _{ON}	Turn-On				-	-	90	ns				
t _{d(ON)}	_	Delay Time			-	12	-	ns				
t _r	Rise Time		$V_{DD} = 50V,$	I _D = 41A R _{GS} = 11.0Ω	-	48	-	ns				
t _{d(OFF)}	Fall Time	Delay Time	$v_{GS} = 10v$,	$R_{GS} = 11.022$	-	24 27	-	ns				
t _f	Turn-Off	Timo			-	21	- 77	ns				
t _{OFF}	-				-		11	ns				
Drain-Sol		de Characteristics	1 44.0			-	4.05	14				
V _{SD}	Source to	Drain Diode Voltage	$I_{SD} = 41A$		-	-	1.25	V				
	Reverse	Recovery Time	$I_{SD} = 21A$	$dl_{r} = /dt = 100 \Lambda /uc$		-	1.0 39					
t _{rr} Q _{RR}		Recovery Time Recovered Charge	$I_{SD} = 41A, dI_{SD}/dt = 100A/\mu s$ $I_{SD} = 41A, dI_{SD}/dt = 100A/\mu s$		-	-	42	ns nC				
Notes: 1: Starting T _J = : 2: Pulse Width =		mH, I _{AS} = 30A.										

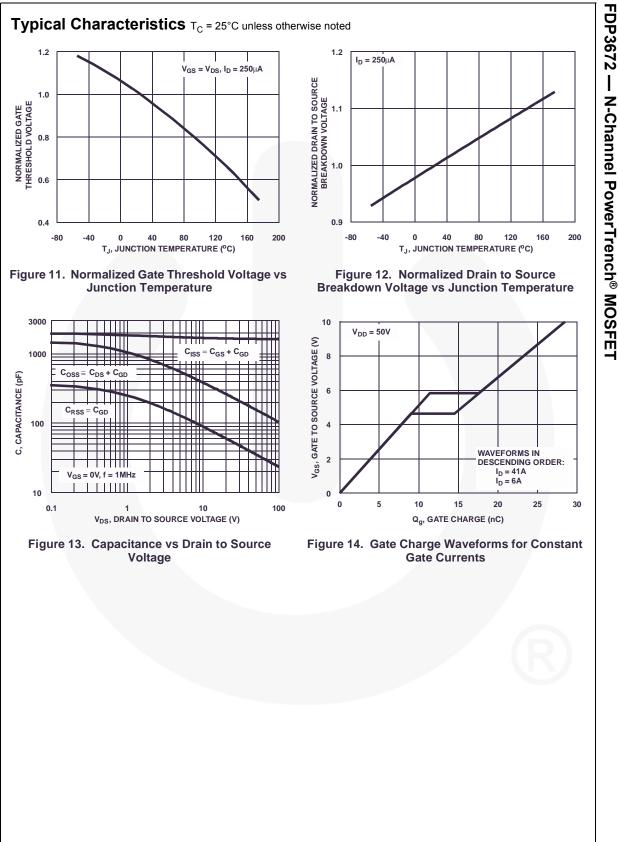
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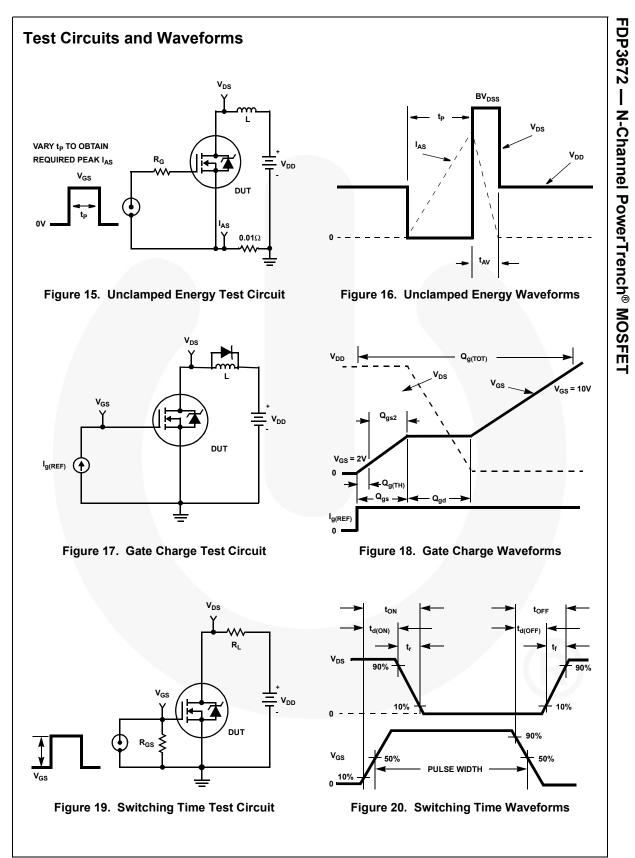


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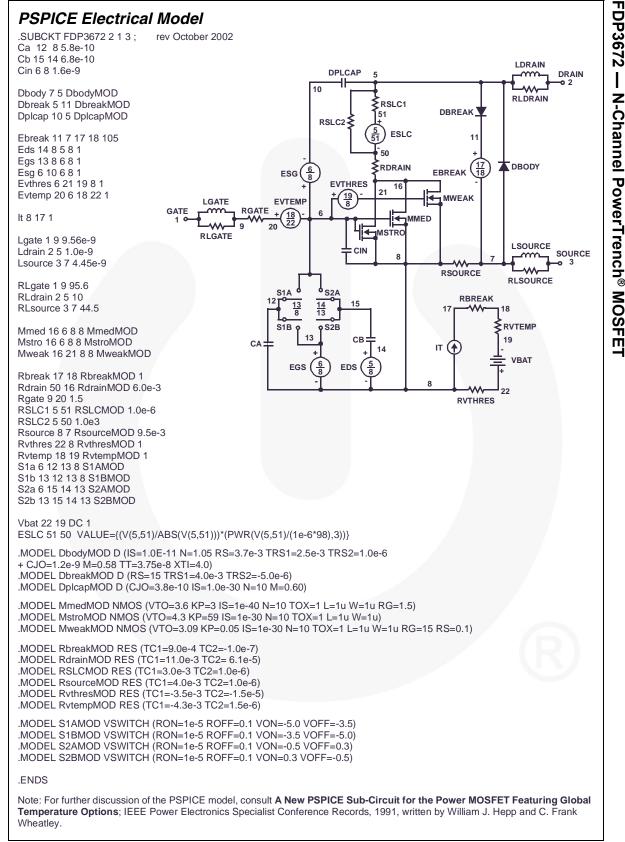


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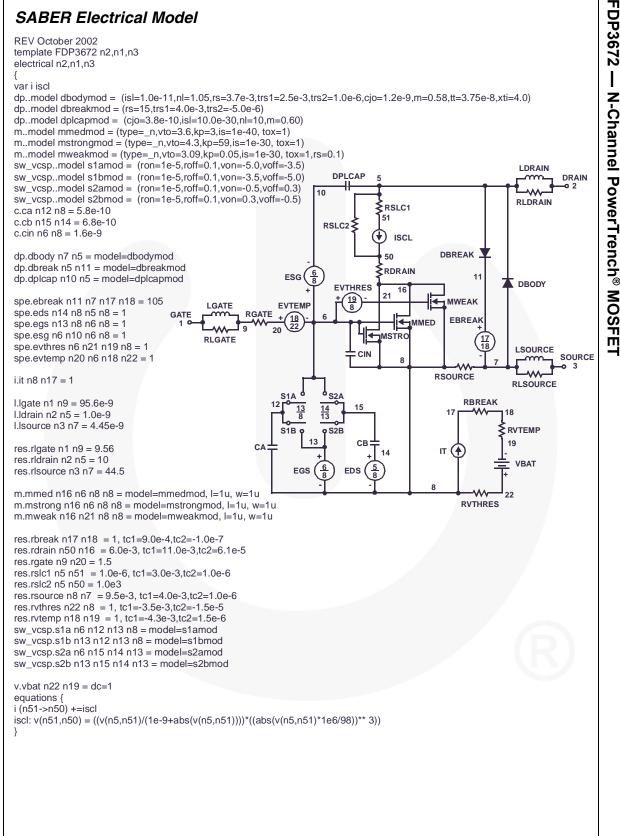


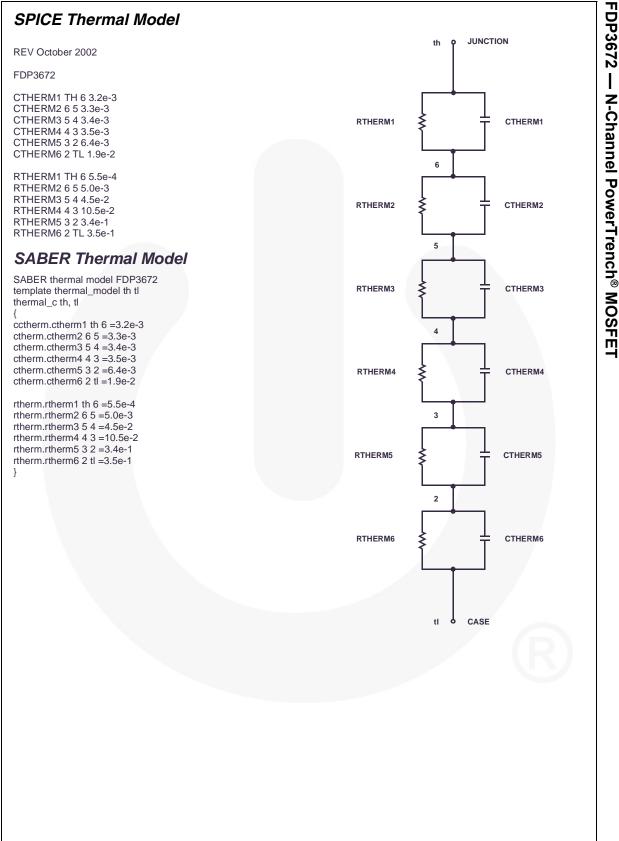


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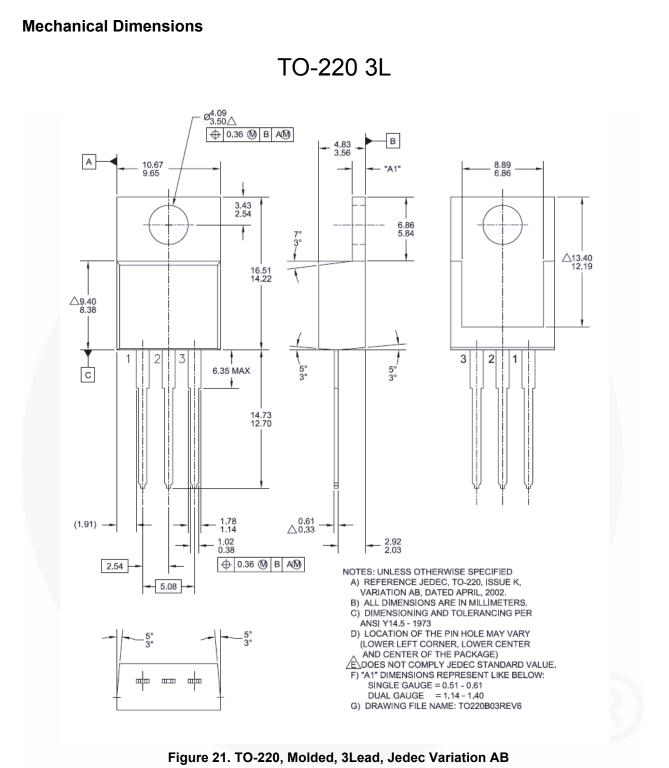


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Dimension in Millimeters



Rev. 166

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